Unit: mm

TOSHIBA Transistor Silicon NPN / PNP Epitaxial Type (PCT Process)

## **TPCP8902**

# Portable Equipment Applications Switching Applications

· Small footprint due to small and thin package

• High DC current gain : PNP  $h_{FE} = 200 \text{ to } 500 \text{ (I}_{C} = -0.2 \text{ A)}$ 

: NPN  $h_{FE} = 200 \text{ to } 500 \text{ (IC} = 0.2 \text{ A)}$ 

• Low collector-emitter saturation : PNP VCE(sat) = -0.20 V(max)

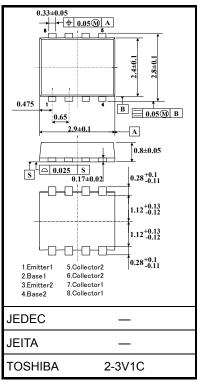
: NPN  $V_{CE (sat)} = 0.14 \text{ V (max)}$ 

• High-speed switching : PNP  $t_f = 40 \text{ ns (typ.)}$ 

: NPN  $t_f = 45 \text{ ns (typ.)}$ 

#### Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating		Unit	
Character	Symbol	PNP	NPN	Offic		
Collector-base voltage	$V_{CBO}$	-30	60	٧		
Collector-emitter voltage		V <sub>CEX</sub>	-30	50	V	
		V <sub>CEO</sub>	-30	30	٧	
Emitter-base voltage	$V_{EBO}$	-7	7	>		
Collector current	DC (Note 1)	Ic	-2.0	2.0	Α	
	Pulse (Note 1)	I <sub>CP</sub>	-8.0	8.0	Λ	
Base current	Base current			0.5	Α	
Collector power dissipation (t = 10s)	Single-device operation		1.67		W	
	Single-device value at dual operation	P <sub>c</sub> (Note 2)	0.91			
Collector power dissipation (DC)	Single-device operation	0.89				
	Single-device value at dual operation	P <sub>C</sub> (Note 2)	0.52		W	
Junction temperature		Tj	150		°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150		°C	



Weight: 0.017 g (typ.)

- Note 1: Please use devices on condition that the junction temperature is below 150°C. Icp= $\pm 8A$  (@  $t \le 100 \,\mu$ s)
- Note 2: Mounted on FR4 board (glass epoxy, 1.6 mm thick, Cu area: 645 mm<sup>2</sup>)
- Note 3: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production 2006-08

Figure 1. Circuit configuration (top view)

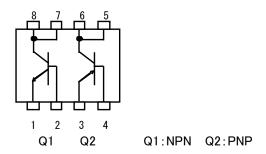
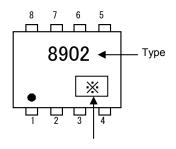


Figure 2. Marking (Note 4)



Lot No.

(Weekly code)

Note 4: ● on lower left on the marking indicates Pin 1.

Weekly code: (Three digits)

Week of manufacture
(01 for first week of year, continues up to 52 or 53)

Year of manufacture
(One low-order digits of calendar year)

### **Electrical Characteristics (Ta = 25°C)**

#### PNP

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I <sub>CBO</sub>	$V_{CB} = -30 \text{ V}, I_E = 0$	_	_	-100	nA
Emitter cut-off current		I <sub>EBO</sub>	$V_{EB} = -7 \text{ V, } I_{C} = 0$	_	_	-100	nA
Collector-emitter breakdown voltage		V (BR) CEO	$I_C = -10 \text{ mA}, I_B = 0$	-30	_	_	V
DC current gain		h <sub>FE</sub> (1)	$V_{CE} = -2 \text{ V}, I_{C} = -0.2 \text{ A}$	200	_	500	
		h <sub>FE</sub> (2)	$V_{CE} = -2 \text{ V}, I_{C} = -0.6 \text{ A}$	125	_	_	
		h <sub>FE</sub> (3)	$V_{CE} = -2 \text{ V}, I_{C} = -2.0 \text{ A}$	40	_	_	
Collector-emitter saturation voltage		V <sub>CE</sub> (sat)	$I_C = -0.6 \text{ A}, I_B = -20 \text{ mA}$	_	_	-0.20	V
Base-emitter saturation voltage		V <sub>BE (sat)</sub>	$I_C = -0.6 \text{ A}, I_B = -20 \text{ mA}$	_	_	-1.10	V
Collector output capacitance		C <sub>ob</sub>	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{MHz}$	_	16.5	_	pF
Switching time	Rise time	t <sub>r</sub>	See Figure 3 circuit diagram V <sub>CC</sub> ≒–18 V, R <sub>L</sub> = 30 Ω I <sub>B1</sub> = I <sub>B2</sub> = 20 mA	_	40	_	
	Storage time	t <sub>stg</sub>		_	280	_	ns
	Fall time	t <sub>f</sub>		_	40	_	

#### NPN

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I <sub>CBO</sub>	$V_{CB} = 60 \text{ V}, I_{E} = 0$	_	_	100	nA
Emitter cut-off current		I <sub>EBO</sub>	$V_{EB} = 7 \text{ V, } I_{C} = 0$	_	_	100	nA
Collector-emitter breakdown voltage		V (BR) CEO	$I_C = 10 \text{ mA}, I_B = 0$	30	_	_	V
DC current gain		h <sub>FE</sub> (1)	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 0.2 A	200	_	500	
		h <sub>FE</sub> (2)	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 0.6 A	125	_	_	
		h <sub>FE</sub> (3)	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 2.0 A	40	_	_	
Collector-emitter saturation voltage		V <sub>CE</sub> (sat)	I <sub>C</sub> = 0.6 A, I <sub>B</sub> = 20 mA	_	_	0.14	V
Base-emitter saturation voltage		V <sub>BE (sat)</sub>	I <sub>C</sub> = 0.6 A, I <sub>B</sub> = 20 mA	_	_	1.10	V
Collector output capacitance		C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1MHz	_	14	_	pF
Switching time	Rise time	t <sub>r</sub>	See Figure 4 circuit diagram V <sub>CC</sub> ≒18 V, R <sub>L</sub> = 30 Ω I <sub>B1</sub> = I <sub>B2</sub> = 20 mA	_	45	_	ns
	Storage time	t <sub>stg</sub>		_	580	_	
	Fall time	t <sub>f</sub>		_	45	_	

Figure 3. Switching Time Test Circuit & Timing Chart

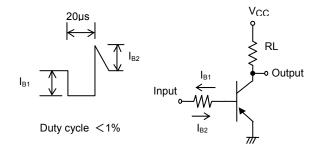
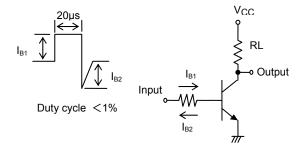
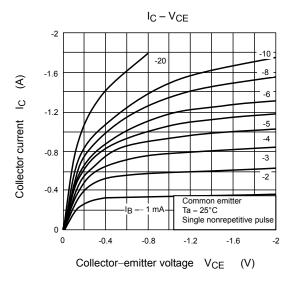


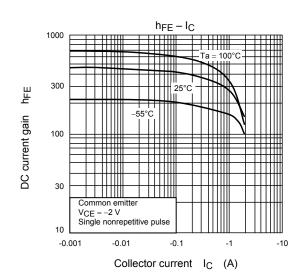
Figure 4. Switching Time Test Circuit & Timing Chart

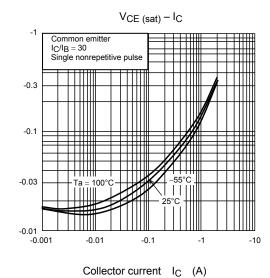


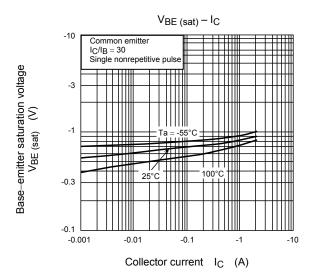
#### **PNP**

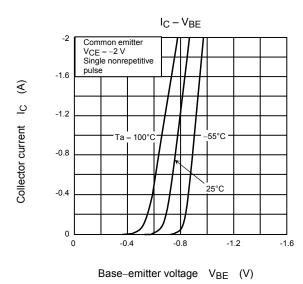
Collector–emitter saturation voltage VCE (sat) (V)

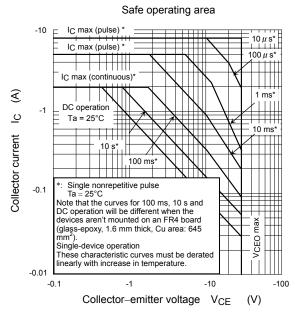








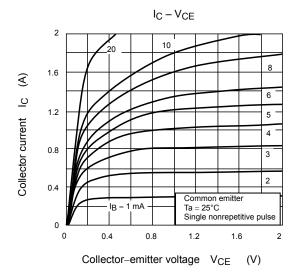


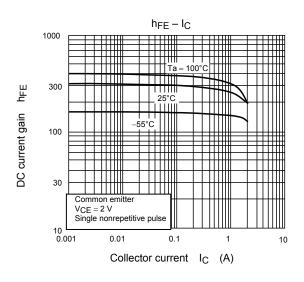


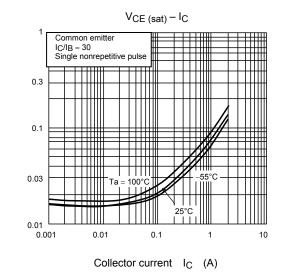
4

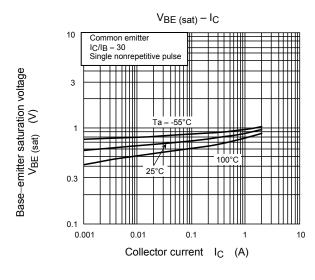
#### **NPN**

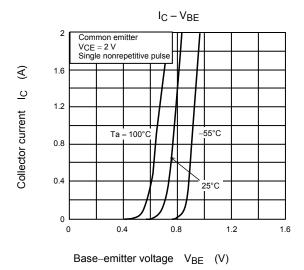
Collector–emitter saturation voltage  $V_{CE}\left( \mathsf{sat}\right) \ \ (V)$ 

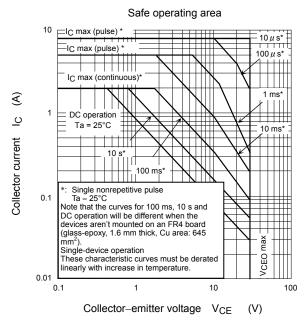


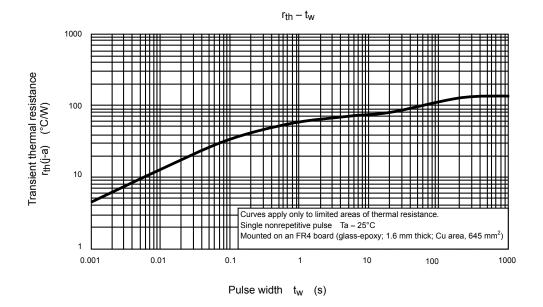




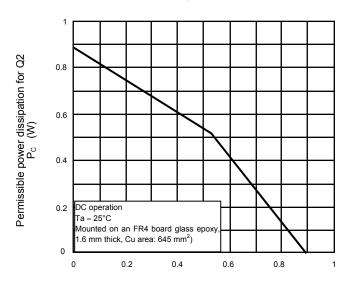








## Permissible Power Dissipation for Simultaneous Operation



Permissible power dissipation for Q1  $$P_{\text{C}}$$  (W)

Collector power dissipation at the single-device operation is 0.89W. Collector power dissipation at the single-device value at dual operation is 0.52W.

Collector power dissipation at the dual operation is set to 1.04W.

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